

Solar Spectrum and Intensity Analysis Under Venus Atmosphere Conditions for Photovoltaics Operation

- ¹Jet Propulsion Laboratory California Institute of Technology ²MicroLink Devices
- 31 Injugacity of Illinois I Irbana
- ³University of Illinois Urbana-Champaign
- ⁴California Institute of Technology

Jonathan Grandidier¹, Alexander Kirk², Mark L. Osowski², Shizhao Fan³, Minjoo L. Lee³, Pawan Gogna¹, Margaret Stevens¹, Phillip Jahelka⁴, Giulia Tagliabue⁴, Harry A. Atwater⁴ and James A. Cutts¹

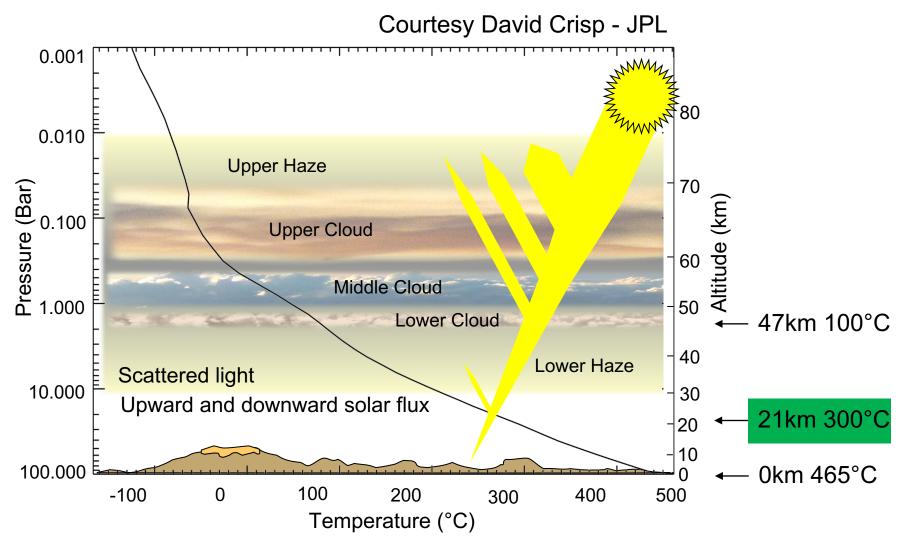
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Outline

- Venus atmosphere and solar illumination
- Solar cell performance under Venus temperature and solar spectrum
- Lifetime testing for survivability at Venus
- Solar cell modelling and optimization
- Conclusion

Venus atmosphere and solar illumination



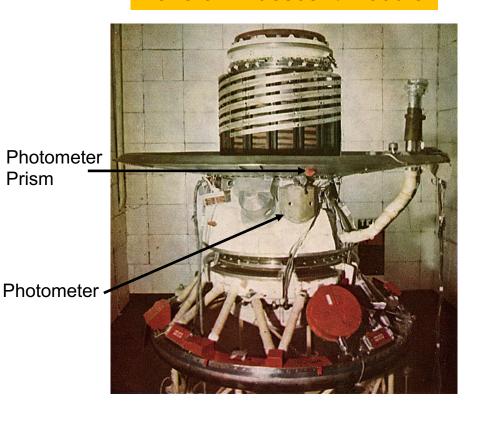
Goal: Solar cell operates optimally at 21km altitude and survives at the surface during limited time excursions

Prism

Venus atmosphere and solar illumination

Venera-11 descent module

View of a plain near Phoebe Regio from Venera 13, taken on 1 March 1982.



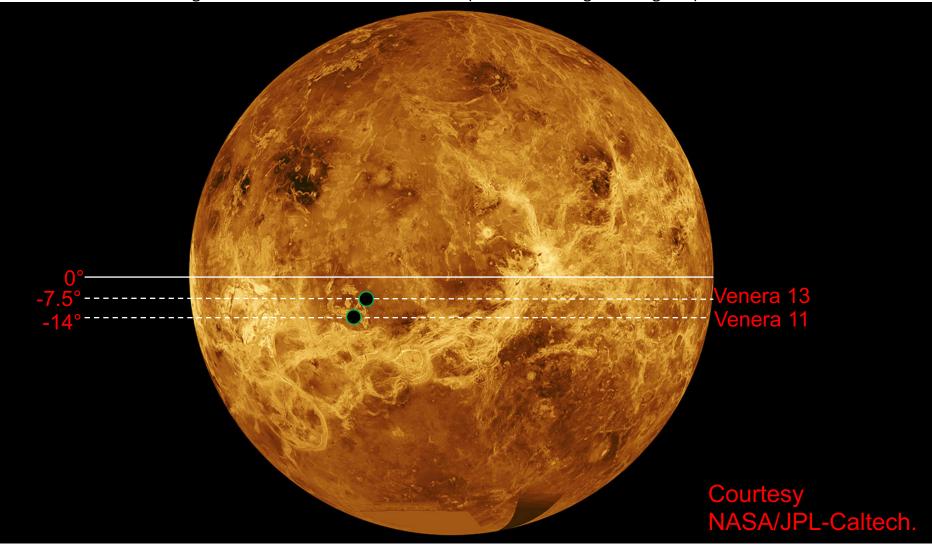


Photometer measurements from Venera 11 and Venera 13 are used to estimate available solar power.

Courtesy Don P. Mitchell

Venus atmosphere and solar illumination

Venus (Hunten, Colin, Donahue, and Moroz, Eds., 1983) - Table II of Larry Colin's chapter (Chapter 2)
Venera 11 entered at -14 degrees latitude at 11:10 AM local solar time (solar zenith angle 17 degrees) on December 25th 1978. Venera 13 entered at -7.5 degrees latitude at 9:27 AM local time (solar zenith angle 38 degrees) on March 1st 1982.

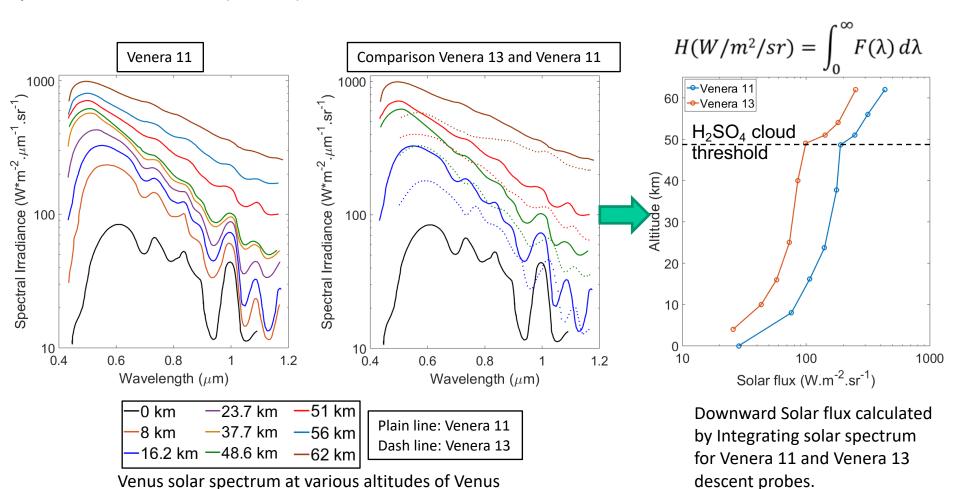


Venus atmosphere and solar illumination

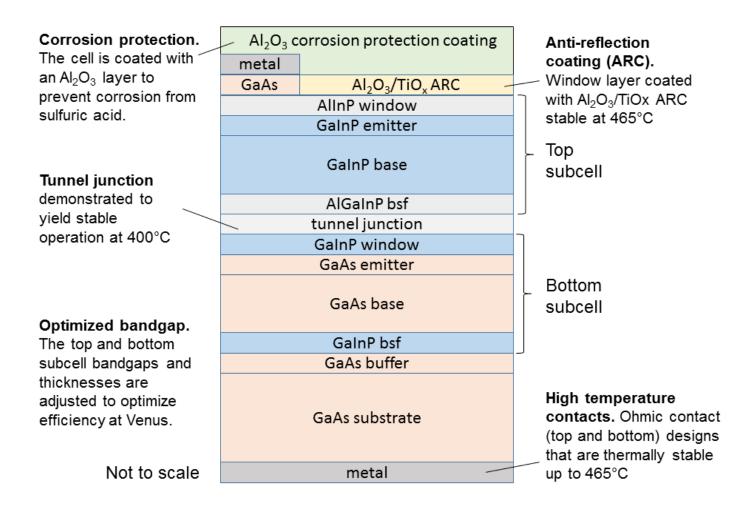
Venus spectrum is very different from Earth and altitude dependent

measured by Venera 11 and Venera 13 descent probes.

Solar zenith angle 17 degrees (Venera 11) and solar zenith angle 38 degrees (Venera 13) changes the path length by $\sim 20\%$, but there is an optical depth 25-40 H_2SO_4 that accounts for a factor of 1.8 in radiance.

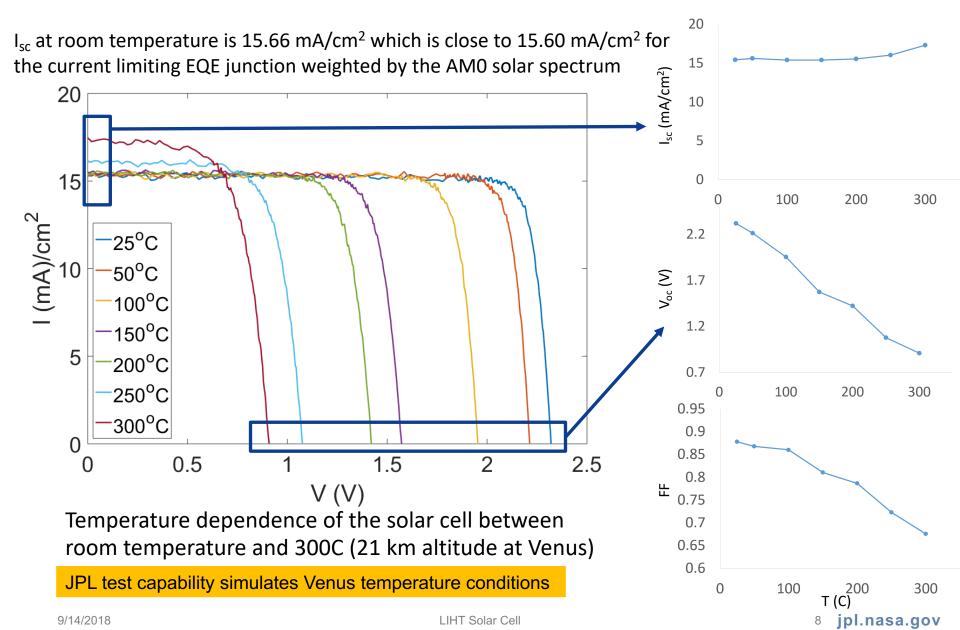


Solar cell performance under Venus temperature and solar spectrum

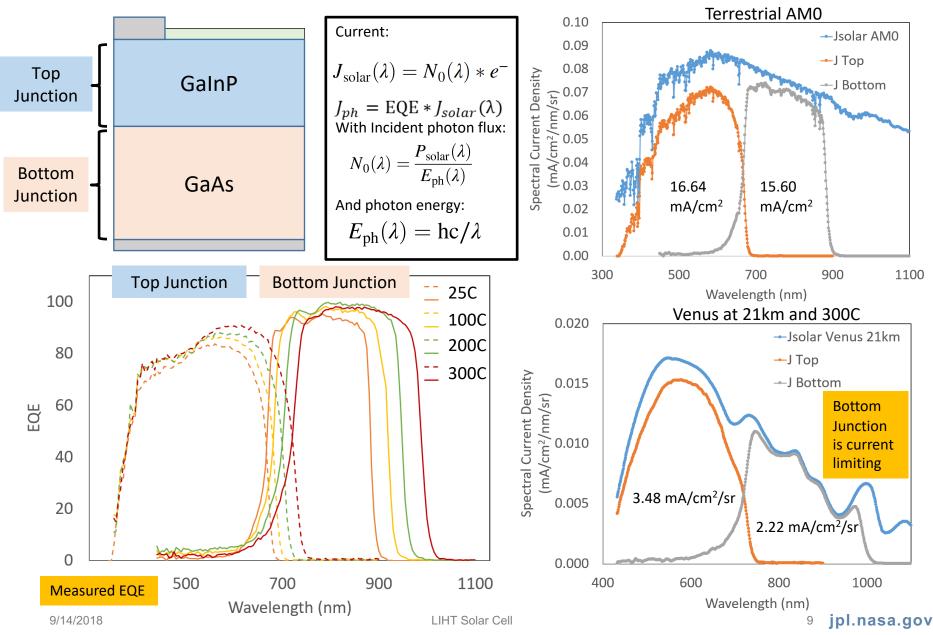


Y. Sun et al., "Thermal stability of GaAs solar cells for high temperature applications," 2016 IEEE 43rd Photovoltaic Specialists Conference (PVSC), Portland, OR, 2016, pp. 2385-2388.

Solar cell performance under Venus temperature and solar spectrum



Solar cell performance under Venus temperature and solar spectrum



Lifetime testing for survivability at Venus

Ag based Metallization 1 Al based Metallization 2

	300°C Venus 21km	465°C Venus Surface
1h		
8h	Metallization 1 and Metallization 2	Metallization 1 and Metallization 2
24h		
1 week		



1 cm² fabricated solar cell

Lifetime Testing setup.

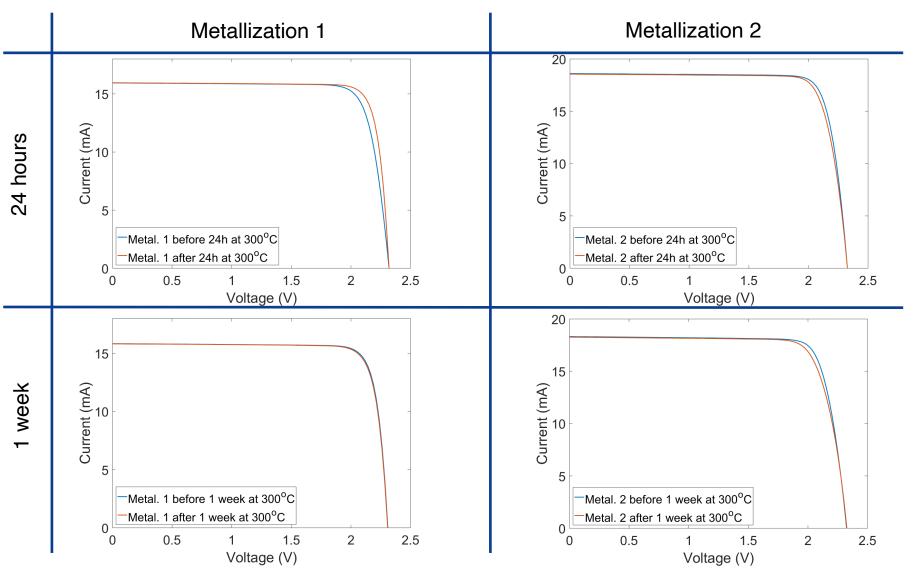
Developed and designed at JPL



Bare solar cells were heated at 300°C (Venus temperature at 21 km altitude) and 465°C (Venus surface temperature) under high vacuum 10⁻⁷ Torr.

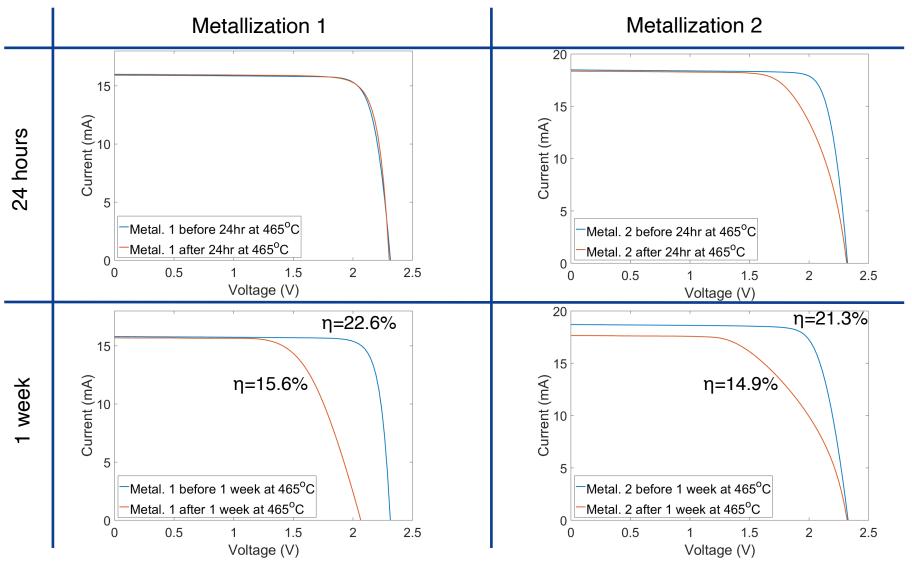
Lifetime testing for survivability at Venus

I-V Before and After 1week at 300°C AM0 1-Sun Light I-V Measurements at MLD

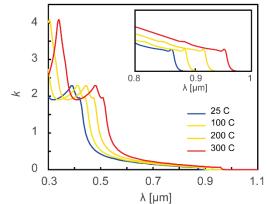


Lifetime testing for survivability at Venus

I-V Before and After 1week at 465°C AM0 1-Sun Light I-V Measurements at MLD



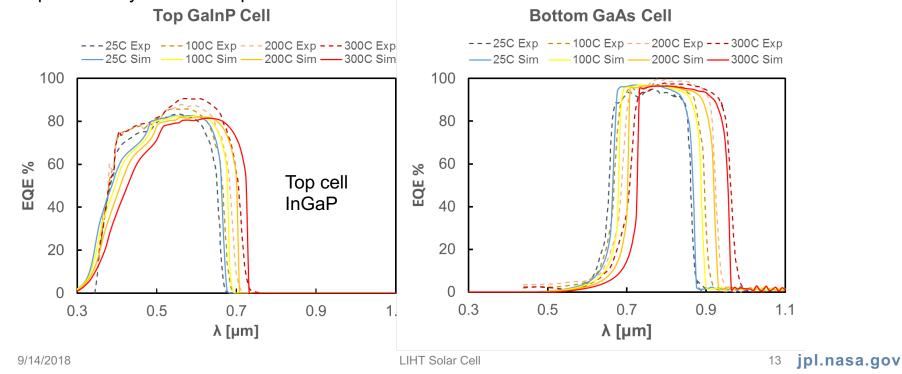
Solar cell modelling and optimization (Caltech)



temperature dependence of the material bandgap, $E_g(T)$ is described by: $E_g(T) = E_{g0} - \frac{\alpha T^2}{\beta + T}$

GaAs temperature-dependent imaginary refractive index, k.

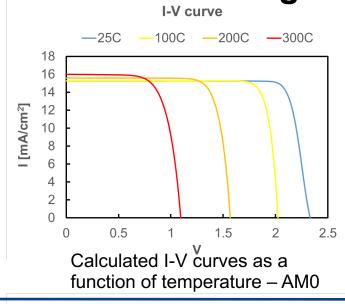
EQE spectra of top and bottom cells as a function of temperature. The dashed lines are the experimentally measured spectra while solid lines are the results of the Sentaurus model:

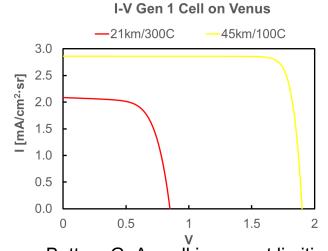


Before Optimization

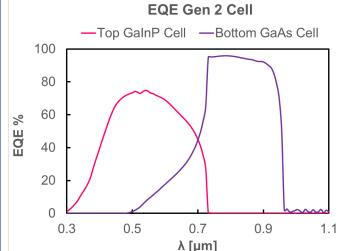
After Optimization

Solar cell modelling and optimization (Caltech)



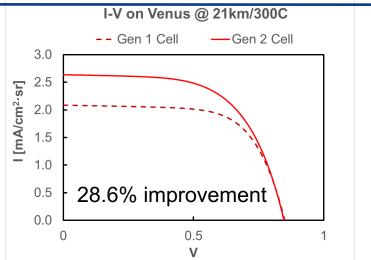


Bottom GaAs cell is current limiting Venus solar spectrum



Gen2 cell has a reduced thickness of the top

GaInP cell to ensure current matching



Conclusion

- Venus solar spectrum and temperature vary significantly with altitude.
- Solar cell needs to be designed for a particular spectrum and temperature therefore particular altitude conditions.
- For Metallization 1, no degradation observed after 1 week at 300°C. Series resistance appears after 1 week at 465°C. For Metallization 2, degradation appears after 24 hours at 465°C.
- Modelling shows an optimal design for a dual junction InGaP/GaAs solar cell at 21km Venus altitude where temperature is 300°C.

Future work:

- Understanding degradation mechanism at high temperature
- Improve metallization for survivability up to 1 month at 465°C
- Fabricate optimized InGaP/GaAs solar cell at 21km Venus altitude/300°C
- J. Grandidier, A. P. Kirk, M. L. Osowski, P. K. Gogna, S. Fan, M. L. Lee, et al., "Low-Intensity High-Temperature (LIHT) Solar Cells for Venus Atmosphere," Accepted, 2018.

Acknowledgements

Jonathan Grandidier jonathan.Grandidier@jpl.nasa.gov



jpl.nasa.gov

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